Notice of References Cited Application/Control No. | Applicant(s)/Patent Under Reexamination SANDVIK ET AL. | Examiner | Art Unit | Page 1 of 1

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	Α	US-			
	В	US-			
	С	US-			
	D	US-			
	Ε	US-			
	F	US-			
	G	US-			
	Н	US-			-
	ı	US-			
	J	US-			
	К	US-			
	L	US-			
	М	US-		:	

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
	0					
	Р					
	Q					
	R					
	s					
	Т			-		

NON-PATENT DOCUMENTS

	Note that I was a second to the second to th							
*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)						
	U	Schalwig et al., "Gas sensitive GaN/AlGaN-heterostructures", Sensors and Actuators B, 2002, vol. 87, pages 425-530.						
	v	Spetz et al., "SiC Based Field Effect Gas Sensors for Industrial Applications", Phys. Stat. Sol. A, 2001, volumn 185, no. 1, pages 15-25.						
	w							
	×							

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)

Dates in MM-YYYYY format are publication dates. Classifications may be US or foreign.